



做中国自主知识产权核心处理器
MCU/DSP/CPU芯片级大脑领导者

深圳市航顺芯片技术研发有限公司
航顺浩瀚处理器(广州)有限公司

国家高新技术企业 深圳龙华2017年八大重点签约引进企业
航顺芯片32位通用MCU之M0 M3 M4世界级超低功耗
性能超稳定 开发工具全兼容进口 软硬件全兼容进口

HK70XX

General Description

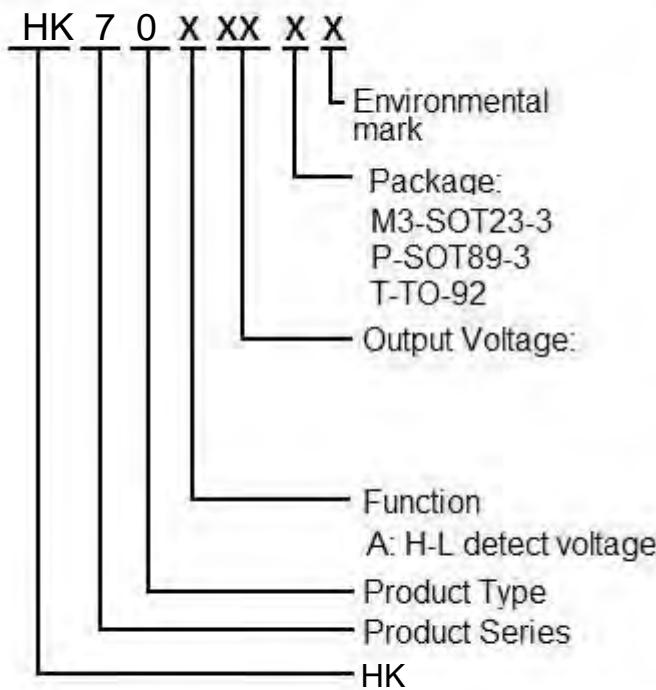
HK70XX Series are a set of three-terminal low power voltage detectors implemented in NMOS technology. Each voltage detector in the series detects a particular fixed voltage ranging from 2.0V to 7.0V. The voltage detectors consist of a high precision and low power consumption standard voltage source, a comparator, hysteresis circuit, and an output driver. NMOS technology ensures low power consumption.

Voltage Detectors , HK70XX Series

Features

- Highly accuracy: $\pm 1\%$
- Low power consumption: TYP 1.8uA ($V_{in}=3V$)
- Detect voltage range: 2.0V~7.0V in 0.1V increments
- Operating voltage range: 1.5V~18V
- Detect voltage temperature characteristics:
TYP $\pm 0.9mV/^\circ C$
- Output configuration: NMOS
- Package: SOT-23-3, SOT-89-3, TO-92

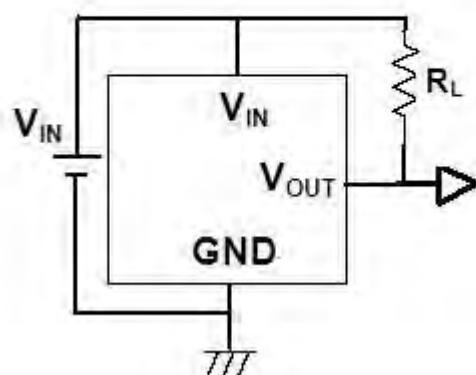
Selection Guide



Typical Application

- battery checkers
- Level selectors
- Power failure detectors
- Microcomputer reset
- Battery backup of Memories

Typical Application Circuit





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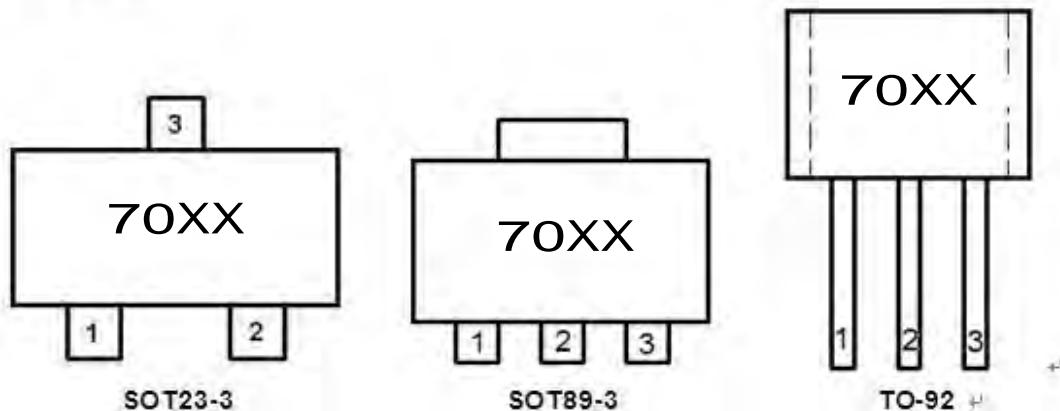
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Selection Table

Part No.	Detectable Voltage	Hysteresis Width	Tolerance	Package	Marking
HK7022	2.2V	0.11V	±2%	TO92 SOT89 SOT23-3	70XX(for TO92) 70XX(for SOT89)
HK7024	2.4V	0.12V	±2%		
HK7027	2.7V	0.135V	±2%		
HK7033	3.3V	0.165V	±2%		
HK7039	3.9V	0.195V	±2%		
HK7044	4.4V	0.22V	±2%		
HK7050	5.0V	0.25V	±2%		

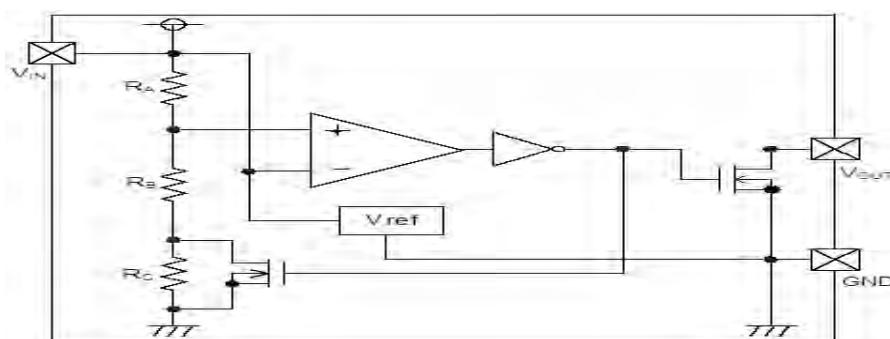
Pin Configuration



Pin Assignment

Pin Number			Pin Name	Functions
SOT-23-3	SOT-89-3	TO-92		
2	3	3	GND	Ground
1	1	1	V _{OUT}	Output Voltage
3	2	2	V _{IN}	Input Voltage

Block Diagram





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Absolute Maximum Ratings

PARAMETER		SYMBOL	RATINGS	UNITS
V_{IN} Input Voltage		V_{IN}	18	V
Output Current		I_{OUT}	50	mA
Output Voltage	NMOS	V_{OUT}	GND-0.3~ V_{IN} +0.3	V
Continuous Total Power Dissipation	SOT23-3	P_D	300	mW
	SOT89-3		500	
	TO-92		500	
Operating Ambient Temperature		T_{Opr}	0~+70	°C
Storage Temperature		T_{stg}	-50~+125	°C
Soldering temperature and time		T_{solder}	260°C, 10s	

Electrical Characteristics ($V_{DET} = 2.0V$ to 7.0V, $T_A = 25^\circ C$, unless otherwise noted)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Units
V_{DET}	Detect Voltage			$V_{DET} \times 0.99$	V_{DET}	$V_{DET} \times 1.01$	V
V_{HYS}	Hysteresis Width			$V_{DET} \times 0.02$	$V_{DET} \times 0.05$	$V_{DET} \times 0.1$	V
I_{IN}	Operating Current	$V_{DET} = 2.0V \sim 2.8V$	$V_{IN} = 3.0V$	-	1.8	3	μA
		$V_{DET} = 2.8V \sim 3.6V$	$V_{IN} = 4.0V$	-	1.8	4	
		$V_{DET} = 3.6V \sim 4.7V$	$V_{IN} = 5.0V$	-	2.1	4	
		$V_{DET} = 4.7V \sim 7.0V$	$V_{IN} = 8.0V$	-	2.5	4	
V_{IN}	Operating Voltage	$V_{DET} = 2.0V$ to 7.0V		0.7	-	18	V
I_{OL}	Output Sink Current	$V_{DET} = 2.0V \sim 2.8V$	$V_{IN} = -V_{DET(S)} - 0.2V$, $V_{OUT} = 0.2V$	0.5			mA
		$V_{DET} = 2.8V \sim 3.6V$	$V_{IN} = -V_{DET(S)} - 0.5V$, $V_{OUT} = 0.3V$	0.5			
		$V_{DET} = 3.6V \sim 4.7V$	$V_{IN} = -V_{DET(S)} - 0.5V$, $V_{OUT} = 0.3V$	1.2			
		$V_{DET} = 4.7V \sim 7.0V$	$V_{IN} = -V_{DET(S)} - 0.5V$, $V_{OUT} = 0.3V$	2.5			
$\Delta V_{DET}/\Delta T_A$	Temperature characteristics	$0^\circ C \leq T_{opr} \leq 70^\circ C$			± 0.9		mV/°C

Note: Use this IC within the stated maximum ratings. Operation beyond these limits may cause degrading or permanent damage to the device.

Functional Description

The HK70xx series is a set of voltage detectors equipped with a high stability voltage reference which is connected to the negative input of a comparator — denoted as V_{REF} in the following figure (Fig. 1). When the voltage drop to the positive input of the comparator (i.e., V_B) is higher than V_{REF} , V_{OUT} goes high, M1 turns off, and V_B is expressed as $V_{BH} = V_{IN} \times (R_B + R_C) / (R_A + R_B + R_C)$. If V_{IN} is decreased so that V_B falls to a value that is less than V_{REF} , the comparator output inverts (from high to low), V_{OUT} goes low, V_C is high, M1 turns on, R_C is bypassed, and V_B becomes: $V_{BL} = V_{IN} \times R_B / (R_A + R_B)$, which is less than V_{BH} . By so doing the comparator out-put will stay low to prevent the circuit from oscillating when $V_B \approx V_{REF}$. If V_{IN} falls below the minimum operating voltage, the output becomes undefined. When V_{IN} goes from low to $V_{IN} \times R_B / (R_A + R_B) > V_{REF}$, the comparator output goes high and V_{OUT} goes high again. The detection voltage is as defined:

$$V_{DET(-)} = (R_A + R_B + R_C) \times V_{REF} / (R_B + R_C)$$

The release voltage is as defined:

$$V_{DET(+)} = (R_A + R_B) \times V_{REF} / R_B$$

The hysteresis width is:

$$V_{HYS} = V_{DET(+)} - V_{DET(-)}$$

Fig.1 demonstrates the NMOS output type with positive output polarity (V_{OUT} is normally high, active low).

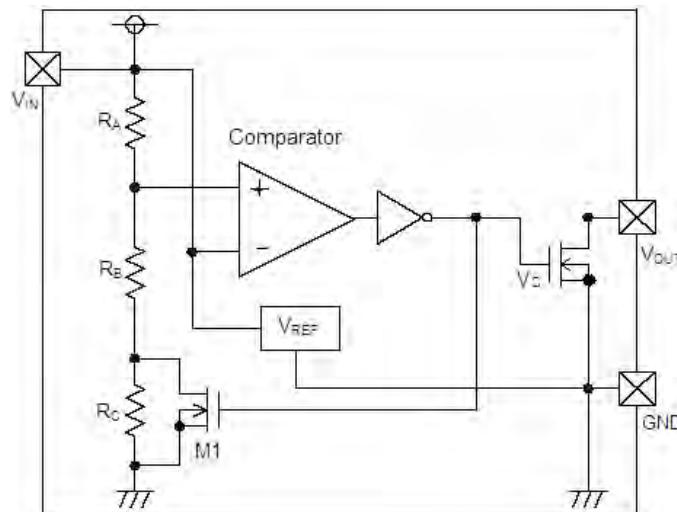
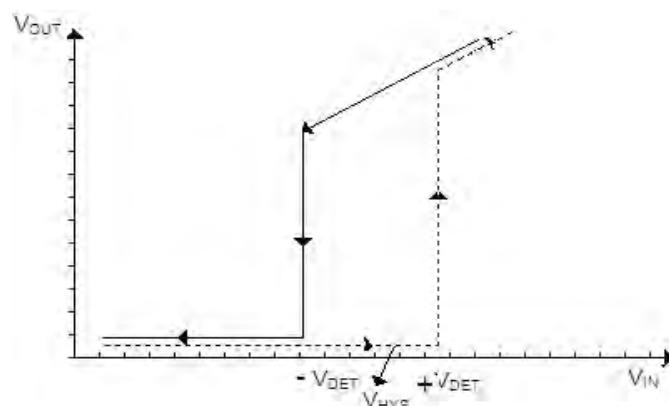


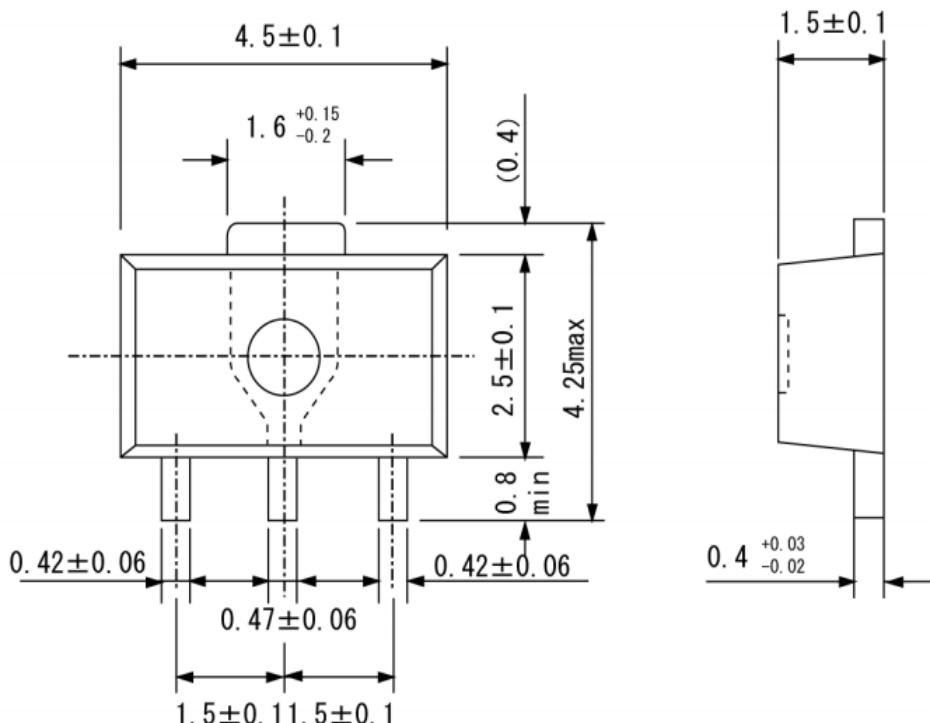
Fig.1 NMOS output voltage detector (HK70XX)

Timing Chart

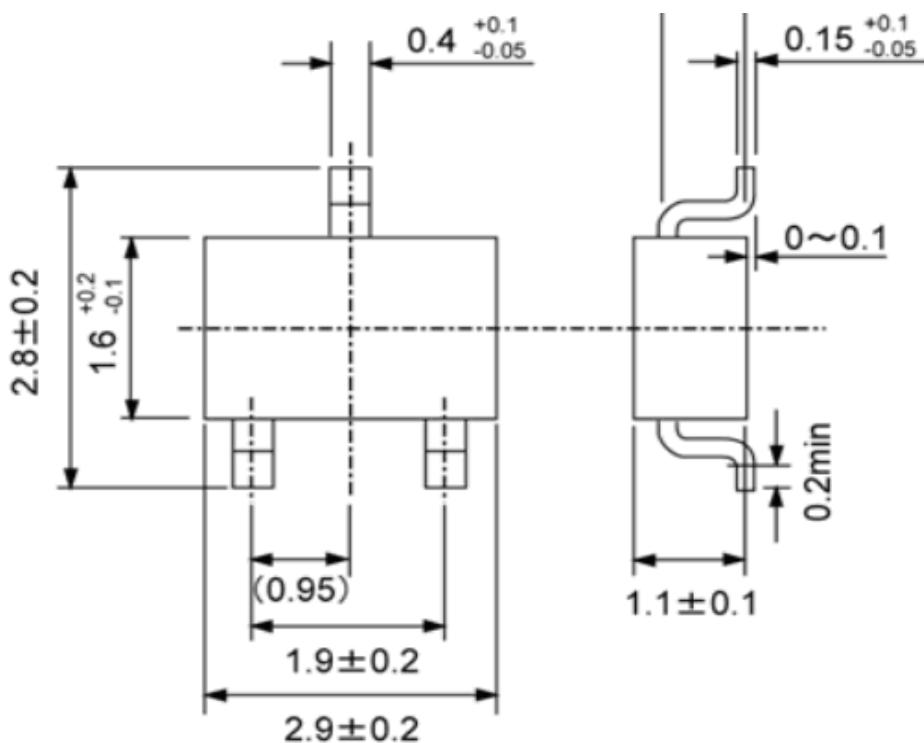


Package Information

● SOT89-3



● SOT23-3





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• TO-92

